

IXTY12N06T

Request a Quote

IXTY12N06T Information



Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



IXTY12N06T Specifications

Manufacturer Part Number	IXTY12N06T
Manufacturer	IXYS
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	TO-252-3, DPak (2 Leads + Tab), SC-63
Series	TrenchMV?
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	60V
Current - Continuous Drain (Id) @ 25°C	12A (Tc)
Drive Voltage (Max Rds On, Min Rds On)	10V
Vgs(th) (Max) @ Id	4V @ 25µA
Gate Charge (Qg) (Max) @ Vgs	3.4nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	256pF @ 25V
Vgs (Max)	$\pm 20 V$
FET Feature	-
Power Dissipation (Max)	33W (Tc)
Rds On (Max) @ Id, Vgs	85 mOhm @ 6A, 10V
Operating Temperature	-55°C ~ 175°C (TJ)
Mounting Type	Surface Mount
Supplier Device Package	TO-252
Package / Case	TO-252-3, DPak (2 Leads + Tab), SC-63
	Report errors?

IXTY12N06T Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

SERVICE BUARANTEE

Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

IXTY12N06T Payment Methods



IXTY12N06T Shipping Methods



If you have any question about IXTY12N06T, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com